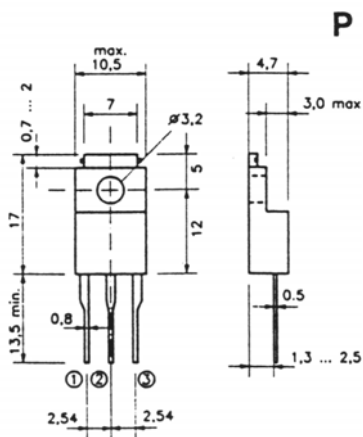


2SJ 176
MOS-FET P-Channel enhanced

Text: Iso
Similar: =2SJ173
Case: M47/c
Prod.:
Hit: Hitachi Europe GmbH

UDS: -60V
UGS: '20V
ID: -15A
IDM: -60A
Ptot: 30W@Tg: 25°C
Tch: 150°C

rds(on) typ: 0,09Ohm@UGS: -10V
IDtyp: -8A
Idss max: -0,25mA@UDS: -50V
rds(on) max: 0,11Ohm@UGS: -10V
UPmin: -1V@UDS: -10V ID: -1m
UPmax: -2V@UDS: -10V ID: -1m
gfs min: 6SmS@UDS: -10V ID: -8A
gfs typ: 9,5SmS@UDS: -10V ID: -8A
t_{on} typ: 135ns
t_{off} typ: 380ns
IGSS: '10'@UGS: '16V



Pin1: Gate
Pin2: Drain
Pin3: Source